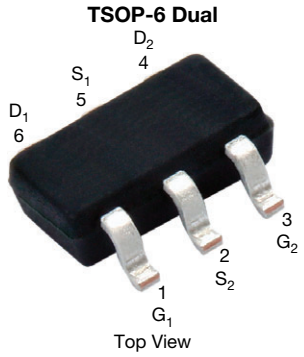
THE DATASHEET OF

SI3552DV-T1-GE3

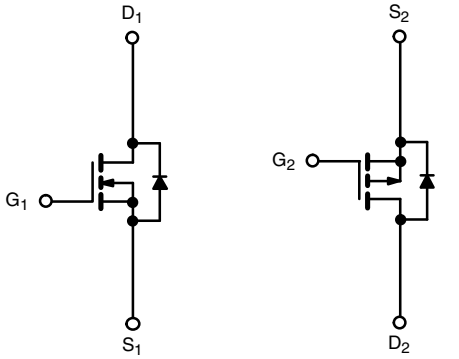
N- and P-Channel 30 V (D-S) MOSFET



FEATURES

- TrenchFET® power MOSFET
- 100 % R_g tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free
RoHS COMPLIANT
HALOGEN FREE Available



PRODUCT SUMMARY		
	N-CHANNEL	P-CHANNEL
V_{DS} (V)	30	-30
$R_{DS(on)}$ (Ω) at V_{GS} = ± 10 V	0.105	0.200
$R_{DS(on)}$ (Ω) at V_{GS} = ± 4.5 V	0.175	0.360
Q_g typ. (nC)	2.1	2.4
I_D (A) [a]	2.5	-1.8
Configuration	N- and p-pair	

ORDERING INFORMATION	
Package	TSOP-6
Lead (Pb)-free	Si3552DV-T1-E3
Lead (Pb)-free and halogen-free	Si3552DV-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	N-CHANNEL	P-CHANNEL	UNIT
Drain-source voltage		V_{DS}	30	-30	V
Gate-source voltage		V_{GS}	± 20	± 20	
Continuous drain current (T_J = 150 °C) [a, b]	T_A = 25 °C	I_D	2.5	-1.8	A
	T_A = 70 °C		2	-1.2	
Pulsed drain current		I_{DM}	8	-7	
Continuous source current (diode conduction) [a, b]		I_S	1.05	-1.05	
maximum power dissipation [a, b]	T_A = 25 °C	P_D	1.15		W
	T_A = 70 °C		0.73		
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150		°C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient [a]	t ≤ 5 s	R_{thJA}	93	110	°C/W
	Steady state		130	150	
Maximum junction-to-lead	Steady state	R_{thJL}	75	90	

Notes

a. Surface mounted on FR4 board

b. t ≤ 5 s

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Gate threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	N-Ch	1	-	-	V
		V_{DS} = V_{GS}, I_D = -250 µA	P-Ch	-1	-	-	
Gate-body leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	N-Ch	-	-	± 100	nA
			P-Ch	-	-	± 100	
Zero gate voltage drain current	I_{DSS}	V_{DS} = 24 V, V_{GS} = 0 V	N-Ch	-	-	1	µA
		V_{DS} = -24 V, V_{GS} = 0 V	P-Ch	-	-	-1	
		V_{DS} = 24 V, V_{GS} = 0 V, T_J = 55 °C	N-Ch	-	-	5	
		V_{DS} = -24 V, V_{GS} = 0 V, T_J = 55 °C	P-Ch	-	-	-5	
On-state drain current [a]	$I_{D(on)}$	V_{DS} = 5 V, V_{GS} = 10 V	N-Ch	5	-	-	A
		V_{DS} = -5 V, V_{GS} = -10 V	P-Ch	-5	-	-	
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 2.5 A	N-Ch	-	0.085	0.105	Ω
		V_{GS} = -10 V, I_D = -1.8 A	P-Ch	-	0.165	0.200	
		V_{GS} = 4.5 V, I_D = 2 A	N-Ch	-	0.140	0.175	
		V_{GS} = -4.5 V, I_D = -1.2 A	P-Ch	-	0.298	0.360	
Forward transconductance [a]	g_{fs}	V_{DS} = 10 V, I_D = 2.5 A	N-Ch	-	4.3	-	S
		V_{DS} = -15 V, I_D = -1.8 A	P-Ch	-	2.4	-	
Diode forward voltage [a]	V_{SD}	I_S = 1.05 A, V_{GS} = 0 V	N-Ch	-	0.81	1.1	V
		I_S = -1.05 A, V_{GS} = 0 V	P-Ch	-	-0.83	-1.1	
Dynamic [b]							
Total gate charge	Q_g	N-Channel V_{DS} = 15 V, V_{GS} = 5 V, I_D = 1.8 A P-Channel V_{DS} = -15 V, V_{GS} = -5 V, I_D = -1.8 A	N-Ch	-	2.1	3.2	nC
			P-Ch	-	2.4	3.6	
Gate-source charge	Q_{gs}		N-Ch	-	0.7	-	
			P-Ch	-	0.9	-	
Gate-drain charge	Q_{gd}		N-Ch	-	0.7	-	
			P-Ch	-	0.8	-	
Gate resistance	R_g		N-Ch	0.5	-	2.4	Ω
			P-Ch	3	-	11	
Turn-on delay time	$t_{d(on)}$	N-Channel V_{DD} = 15 V, R_L = 15 Ω I_D ≅ 1 A, V_{GEN} = 10 V, R_g = 6 Ω P-Channel V_{DD} = -15 V, R_L = 15 Ω I_D ≅ -1 A, V_{GEN} = -10 V, R_g = 6 Ω	N-Ch	-	7	11	ns
			P-Ch	-	8	12	
Rise time	t_r		N-Ch	-	9	14	
			P-Ch	-	12	18	
Turn-off delay time	$t_{d(off)}$		N-Ch	-	13	20	
			P-Ch	-	12	18	
Fall time	t_f		N-Ch	-	5	8	
			P-Ch	-	7	11	
Source-drain reverse recovery time	t_{rr}	I_F = 1.05 A, di/dt = 100 A/µs	N-Ch	-	35	60	
		I_F = -1.05 A, di/dt = 100 A/µs	P-Ch	-	30	60	

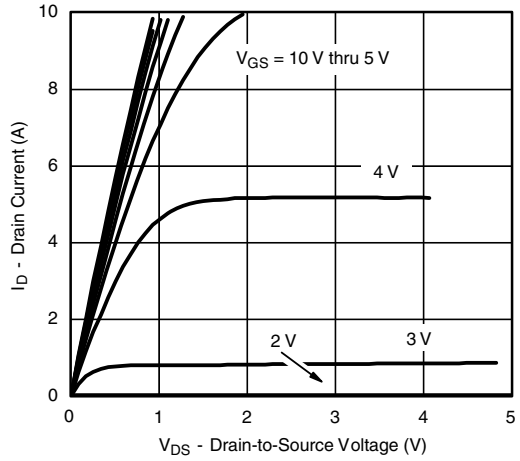
Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

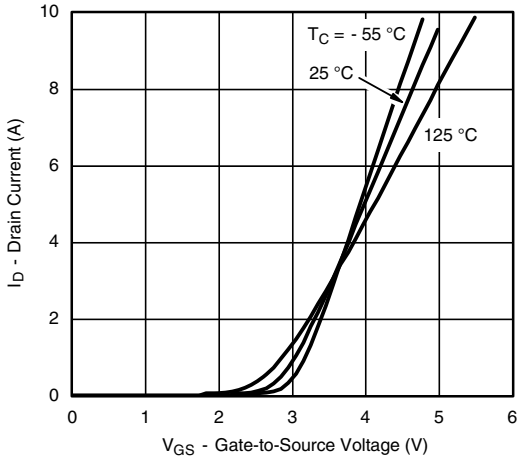
b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

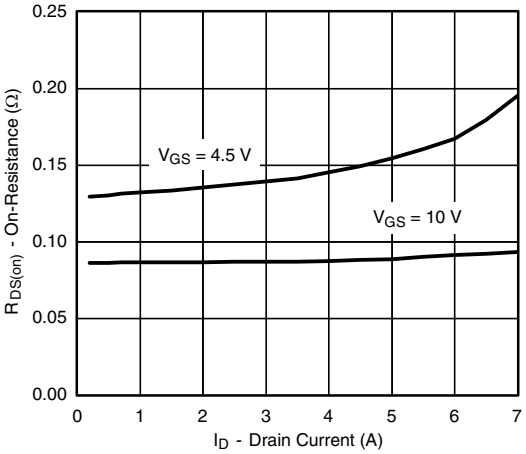
N-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



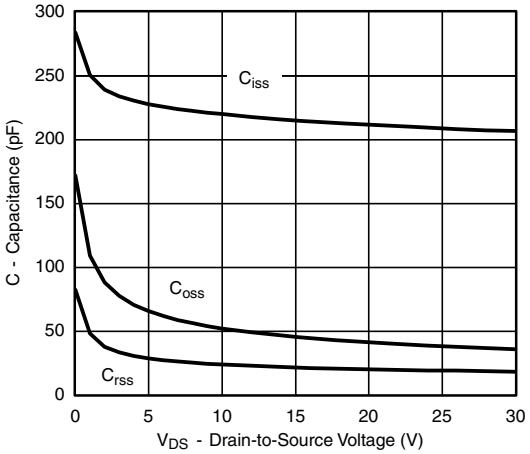
Output Characteristics



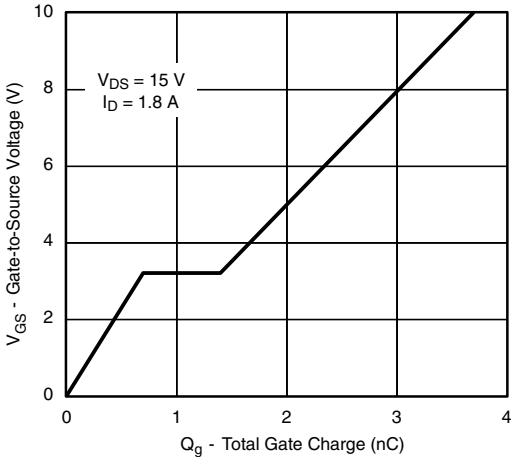
Transfer Characteristics



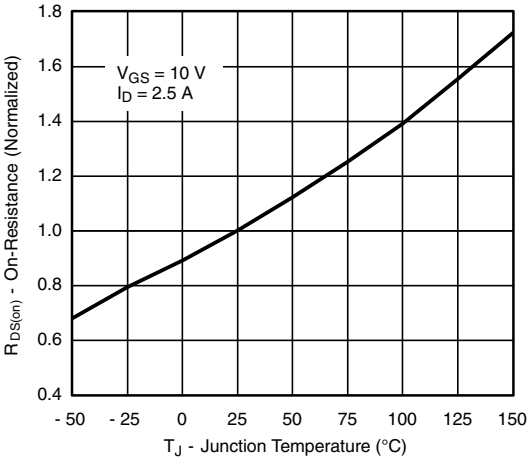
On-Resistance vs. Drain Current



Capacitance

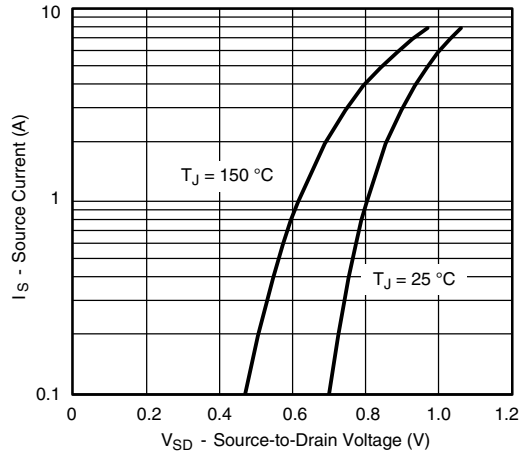


Gate Charge

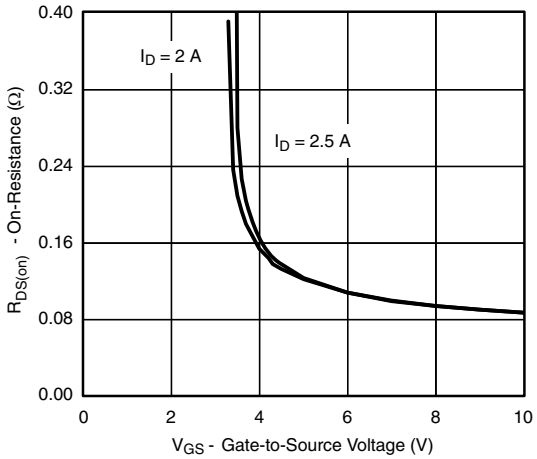


On-Resistance vs. Junction Temperature

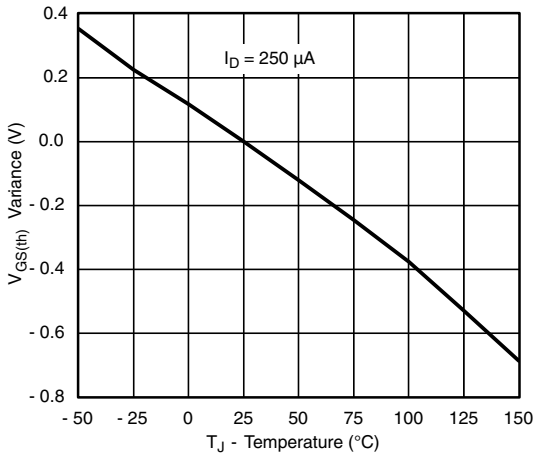
N-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



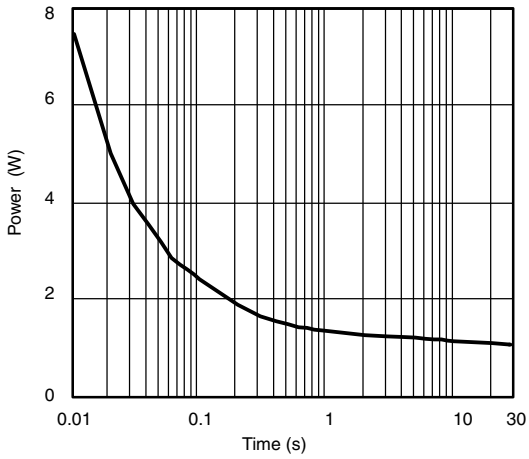
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

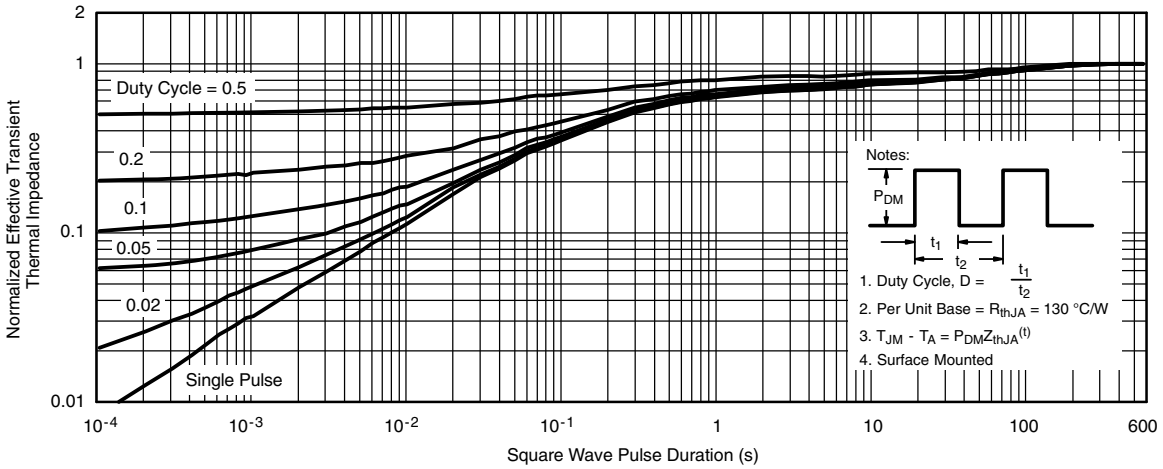


Threshold Voltage

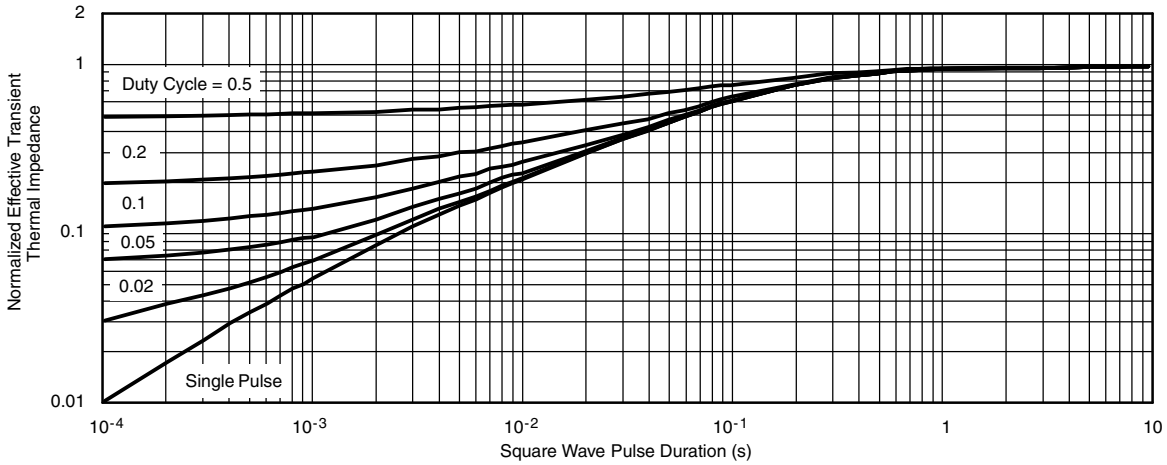


Single Pulse Power (Junction-to-Ambient)

N-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

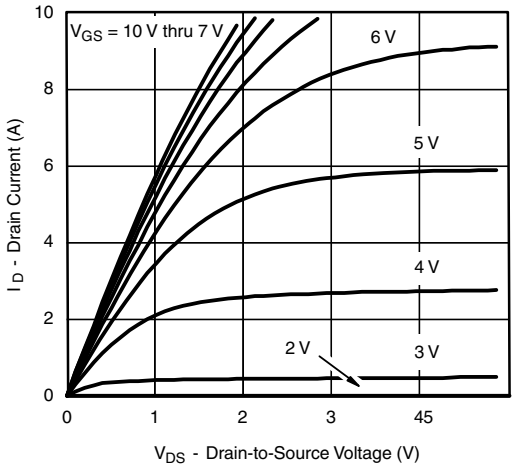


Normalized Thermal Transient Impedance, Junction-to-Ambient

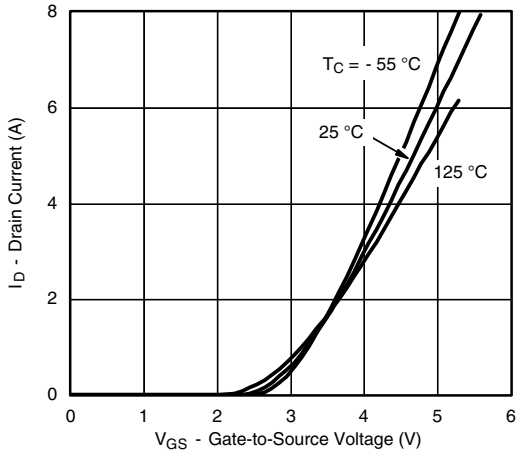


Normalized Thermal Transient Impedance, Junction-to-Foot

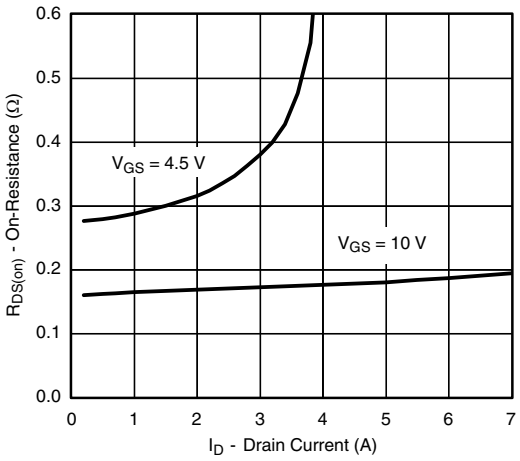
P-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



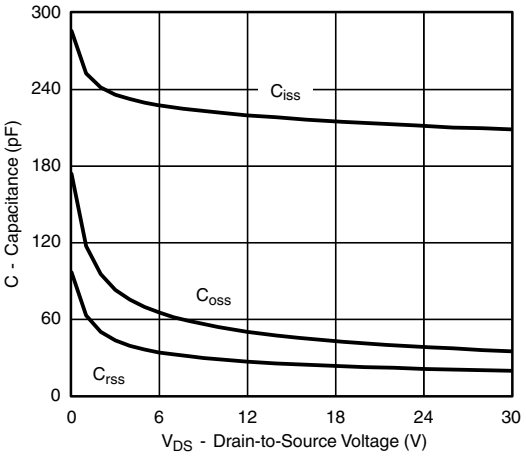
Output Characteristics



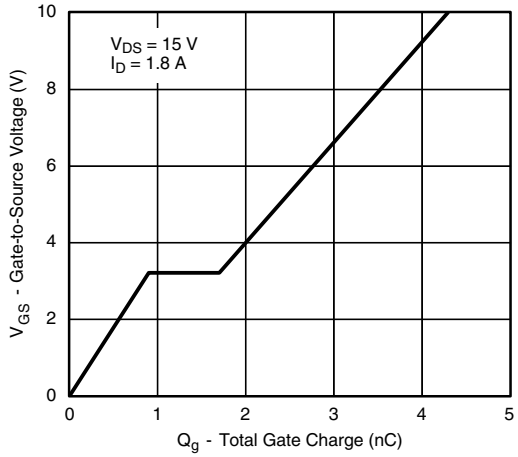
Transfer Characteristics



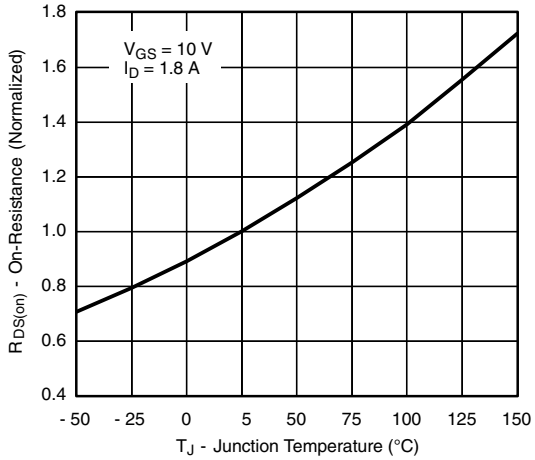
On-Resistance vs. Drain Current



Capacitance

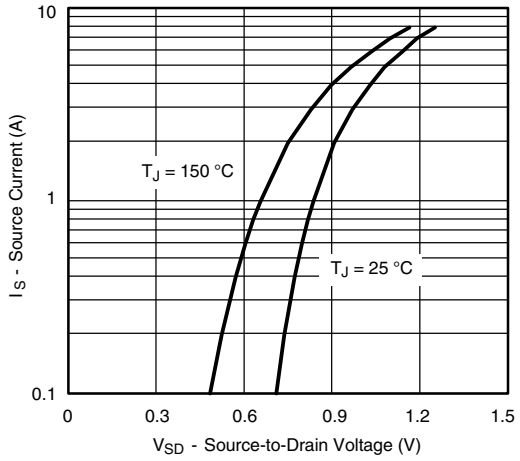


Gate Charge

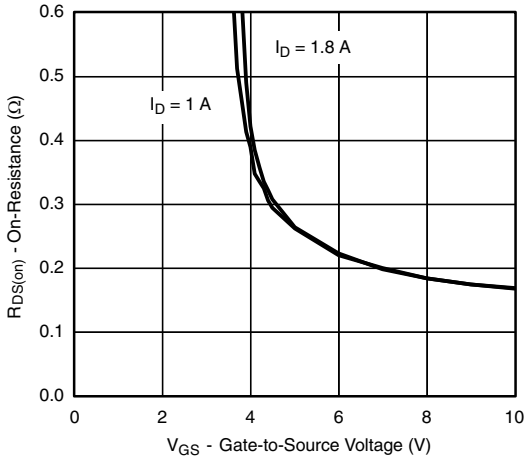


On-Resistance vs. Junction Temperature

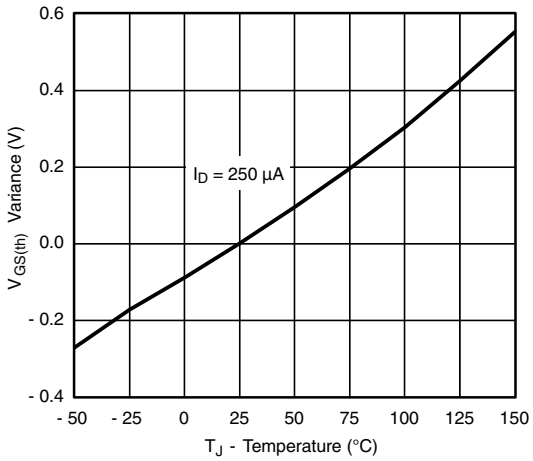
P-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



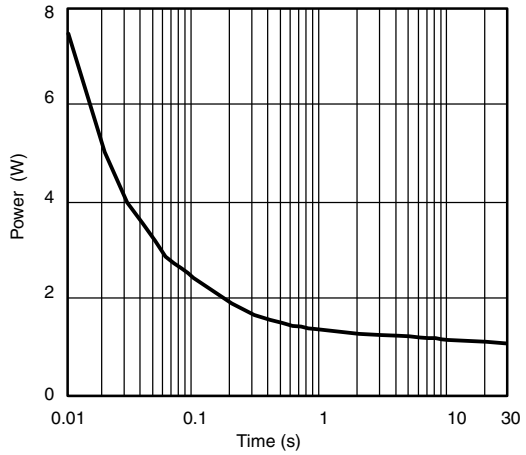
Source-Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

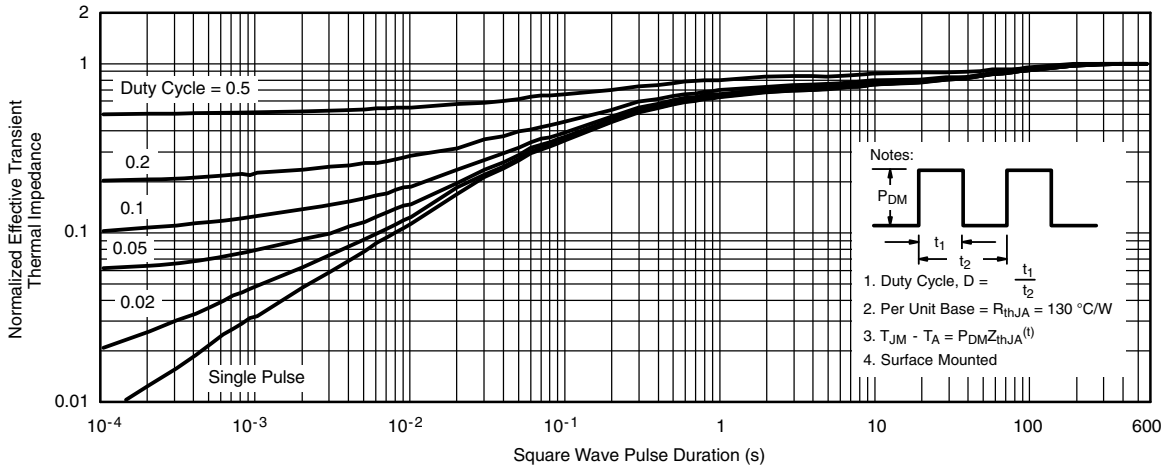


Threshold Voltage

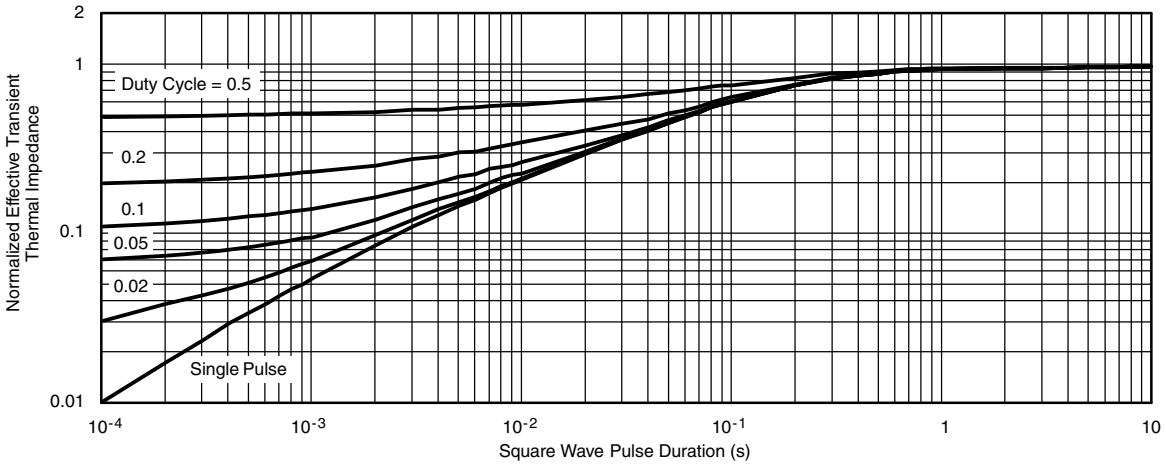


Single Pulse Power (Junction-to-Ambient)

P-CHANNEL TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



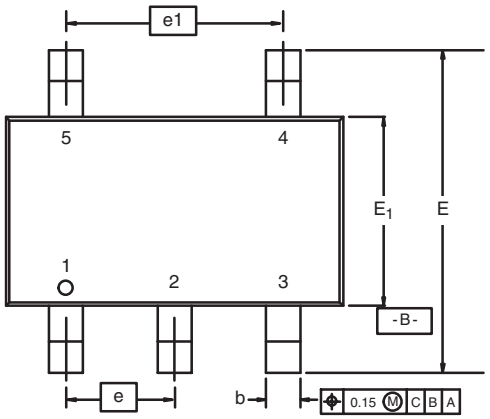
Normalized Thermal Transient Impedance, Junction-to-Ambient



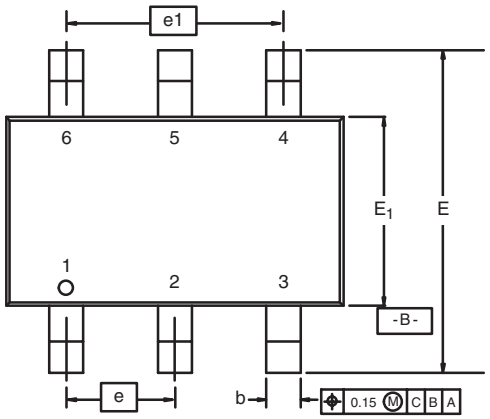
Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?70971.

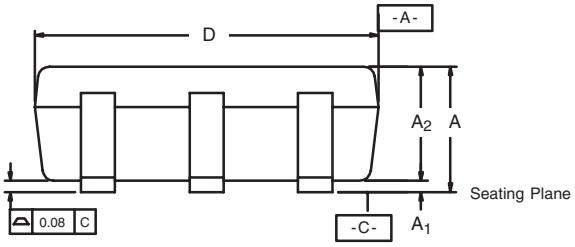
TSOP: 5/6–LEAD
JEDEC Part Number: MO-193C

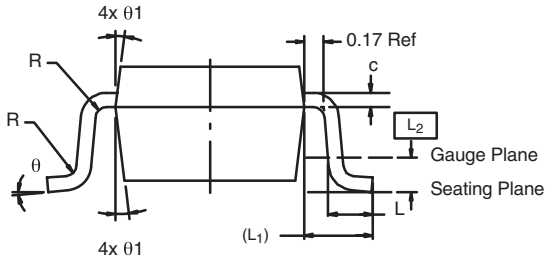


5-LEAD TSOP



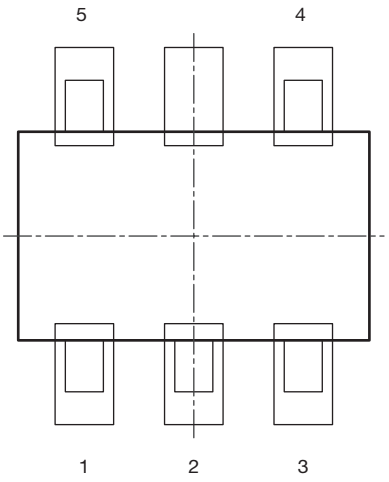
6-LEAD TSOP



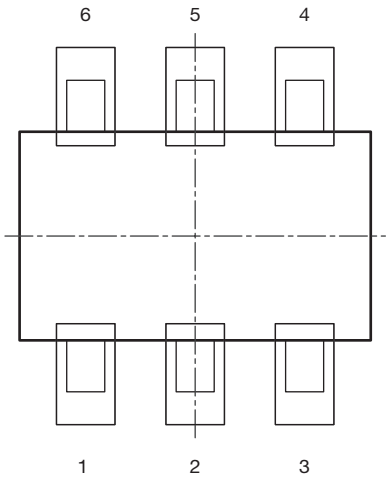


Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A_1	0.01	-	0.10	0.0004	-	0.004
A_2	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E_1	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e_1	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L_1	0.60 Ref			0.024 Ref		
L_2	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
θ_1	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540						

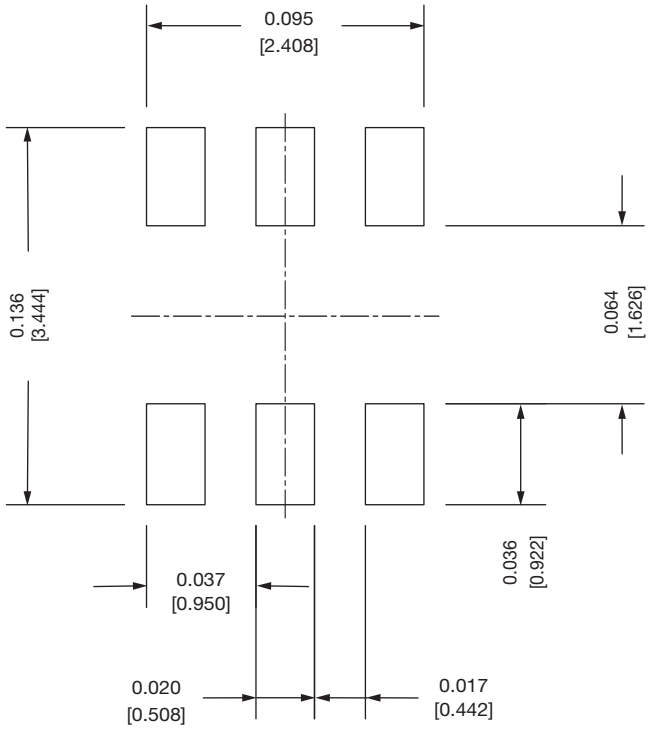
Recommended Land Pattern For TSOP-5L / TSOP-6L



TSOP 5L



TSOP 6L



Note

- All dimensions are in inches (millimeter)

ECN: C22-0860-Rev. B, 24-Oct-2022 DWG: 3010

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- View SI3552DV-T1-GE3 on WIN SOURCE
- Vishay Information

Optimize Your Supply Chain with WIN SOURCE Solutions

- Global Sourcing Solution
- Obsolete Management
- Cost Control Management
- Shortage Management
- Alternative Solution
- Excess Inventory Management